

Low IR Schottky barrier diode

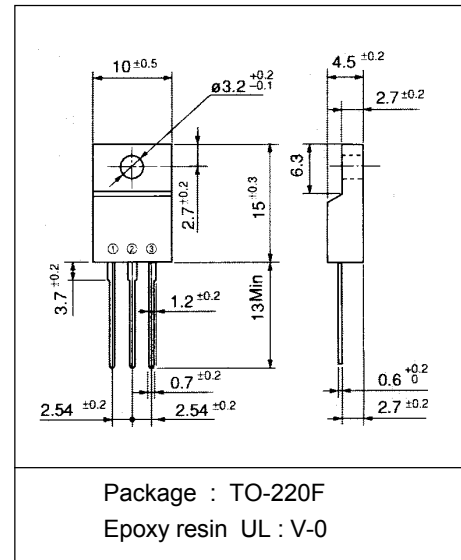
Features

- Low IR
- Low VF
- Center tap connection

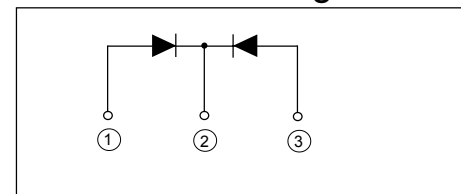
Applications

- High frequency operation
- DC-DC converters
- AC adapter

Outline drawings, mm



Connection diagram



Maximum ratings and characteristics

Maximum ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak surge reverse voltage	V_{RSM}	tw=500ns, duty=1/40	60	V
Repetitive peak reverse voltage	V_{RRM}		60	V
Isolating voltage	Viso	Terminals-to-Case, AC. 1min.	1500	V
Average output current	I_o	Square wave, duty=1/2 $T_c=124^{\circ}C$	10 *	A
Non-repetitive surge current	I_{FSM}	Sine wave 10ms	125	A
non-repetitive reverse surge power dissipation	PRM	tw=10μs, $T_j=25^{\circ}C$	330	W
Operating junction temperature	T_j		+150	$^{\circ}C$
Storage temperature	T_{stg}		-40 to +150	$^{\circ}C$

* Out put current of center tap full wave connection

Electrical characteristics (at $T_a=25^{\circ}C$ Unless otherwise specified)

Item	Symbol	Conditions	Max.	Unit
Forward voltage **	V_F	$I_F=5A$	0.68	V
Reverse current **	I_R	$V_R=60V$	150	μA
Thermal resistance	Rth(j-c)	Junction to case	3.5	$^{\circ}C/W$

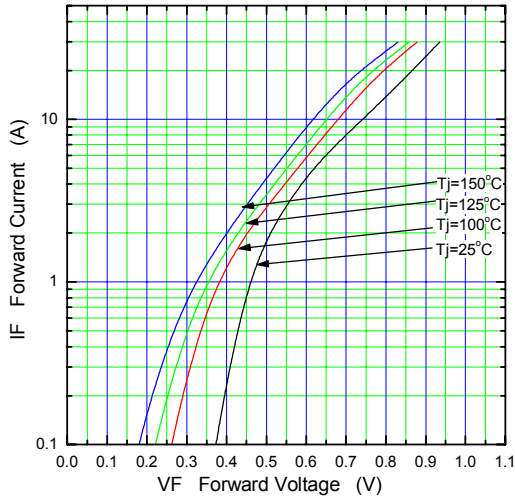
**Rating per element

Mechanical characteristics

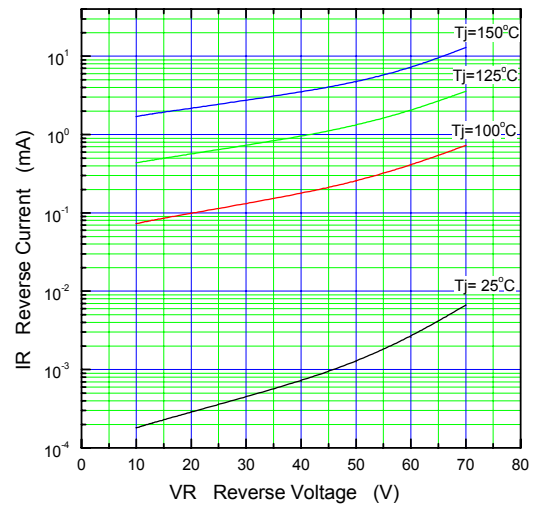
Mounting torque	Recommended torque	0.3 to 0.5	N·m
Approximate mass		2	g

■ Characteristics

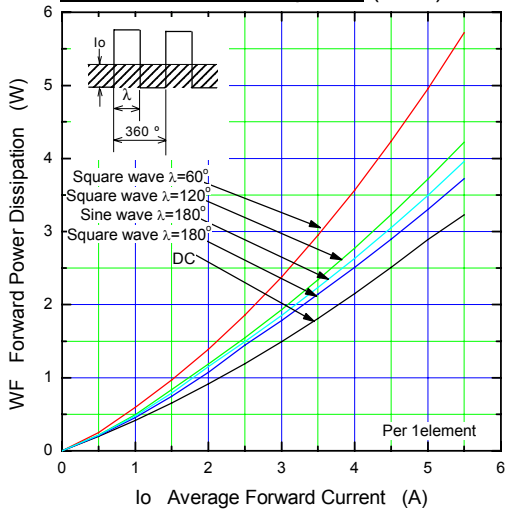
Forward Characteristic (typ.)



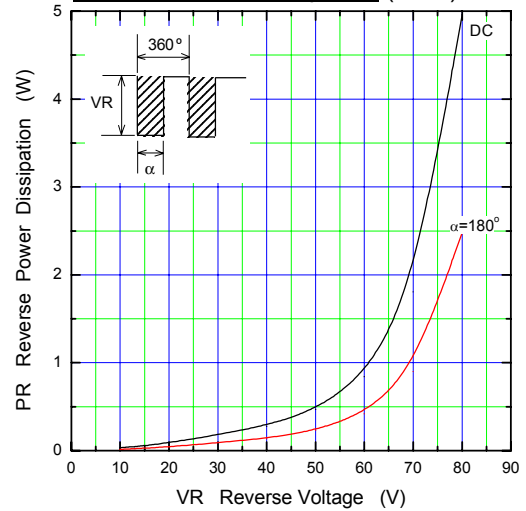
Reverse Characteristic (typ.)



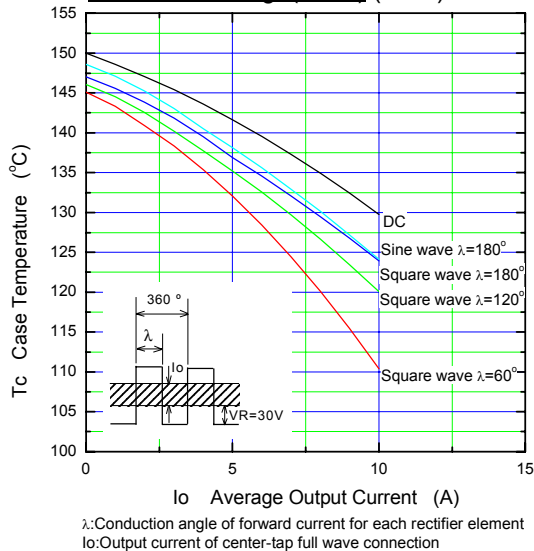
Forward Power Dissipation (max.)



Reverse Power Dissipation (max.)



Current Derating (Io-Tc) (max.)



Junction Capacitance Characteristic (max.)

